

# 60V N-CHANNEL SELF PROTECTED ENHANCEMENT MODE IntelliFET MOSFET

#### **Product Summary**

Continuous Drain Source Voltage: 60V

On-State Resistance: 500mΩ

Nominal Load Current (V<sub>IN</sub> = 5V): 1.3A

Clamping Energy: 90mJ

#### **Description**

The DIODES™ ZXMS6004FFQ is a self-protected low side IntelliFET™ MOSFET with logic level input. It integrates overtemperature, overcurrent, overvoltage (active clamp) and ESD protected logic level functionality. The ZXMS6004FFQ is ideal as a general purpose switch driven from 3.3V or 5V microcontrollers in harsh environments where standard MOSFETs are not rugged enough.

#### **Applications**

- Especially suited for loads with a high in-rush current such as lamps and motors
- All types of resistive, inductive and capacitive loads in switching applications
- μC compatible power switch for 12V and 24V DC applications
- Automotive rated
- Replaces electromechanical relays and discrete circuits
- Linear mode capability the current-limiting protection circuitry is
  designed to de-activate at low V<sub>DS</sub> to minimize on state power
  dissipation. The maximum DC operating current is therefore
  determined by the thermal capability of the package/board
  combination, rather than by the protection circuitry. This does not
  compromise the product's ability to self-protect at low V<sub>DS</sub>.

#### **Features and Benefits**

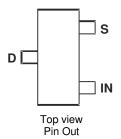
- Compact High Power Dissipation Package
- Low Input Current
- Logic Level Input (3.3V and 5V)
- Short Circuit Protection with Auto Restart
- Over Voltage Protection (Active Clamp)
- Thermal Shutdown with Auto Restart
- Overcurrent Protection
- Input Protection (ESD)
- High Continuous Current Rating
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The ZXMS6004FFQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

#### **Mechanical Data**

- Package: SOT23F
- Package Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish (3)
- Weight: 0.012 grams (Approximate)





# Ordering Information (Note 4)

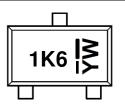
| Part Number   | Part Number Package Marking Reel Size (inches |     | Pool Sizo (inches)  | s) Tape Width (mm) | Packing |         |
|---------------|---|-----|---------------------|--------------------|---------|---------|
| Fait Number   |   |     | neer Size (iliches) | rape width (IIIII) |         | Carrier |
| ZXMS6004FFQTA | SOT23F  | 1K6 | 7                   | 12                 | 3,000   | Reel    |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

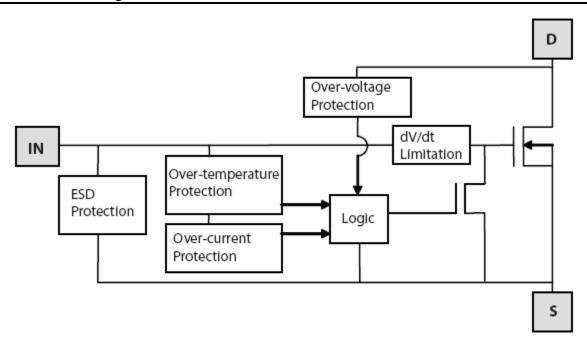


# **Marking Information**



1K6 = Product Type Marking Code Y or  $\overline{Y}$ : Year: 0 to 9 W or  $\overline{W}$ : Week: A to Z: 1 to 26 a to z: 27 to 52 z: Represents 52 & 53 Week

# **Functional Block Diagram**





# **Absolute Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

| Characteristic   | Symbol              | Value                              | Unit |
|--|---------------------|------------------------------------|------|
| Continuous Drain-Source Voltage  | V <sub>DS</sub>     | 60                                 | V    |
| Drain-Source Voltage for Short Circuit Protection  | V <sub>DS(SC)</sub> | 36                                 | V    |
| Continuous Input Voltage   | V <sub>IN</sub>     | -0.5 +6                            | V    |
| Continuous Input Current @-0.2V $\leq$ V <sub>IN</sub> $\leq$ 6V Continuous Input Current @V <sub>IN</sub> $<$ -0.2V or V <sub>IN</sub> $>$ 6V | l <sub>IN</sub>     | No Limit<br>  I <sub>IN</sub>   ≤2 | mA   |
| Pulsed Drain Current @V <sub>IN</sub> = 3.3V   | I <sub>DM</sub>     | 2                                  | Α    |
| Pulsed Drain Current @VIN = 5V   | I <sub>DM</sub>     | 2.5                                | Α    |
| Continuous Source Current (Body Diode)   | ls                  | 1                                  | Α    |
| Pulsed Source Current (Body Diode)   | I <sub>SM</sub>     | 5                                  | Α    |
| Unclamped Single Pulse Inductive Energy,<br>$T_J = +25^{\circ}C$ , $I_D = 0.5A$ , $V_{DD} = 24V$   | Eas                 | 90                                 | mJ   |
| Electrostatic Discharge (Human Body Model)   | V <sub>ESD</sub>    | 4,000                              | V    |
| Charged Device Model   | Vcdm                | 1,000                              | V    |

### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

| Characteristic   | Symbol           | Value        | Unit       |
|--|------------------|--------------|------------|
| Power Dissipation @T <sub>A</sub> = +25°C (Note 5)<br>Linear Derating Factor | PD               | 0.83<br>6.66 | W<br>mW/°C |
| Power Dissipation @T <sub>A</sub> = +25°C (Note 6)<br>Linear Derating Factor | PD               | 1.5<br>12.0  | W<br>mW/°C |
| Thermal Resistance, Junction to Ambient (Note 5)                             | Reja             | 150          | °C/W       |
| Thermal Resistance, Junction to Ambient (Note 6)                             | R <sub>0JA</sub> | 83           | °C/W       |
| Thermal Resistance, Junction to Case (Note 7)                                | Rejc             | 44           | °C/W       |
| Operating Temperature Range  | TJ               | -40 to +150  | °C         |
| Storage Temperature Range  | T <sub>STG</sub> | -55 to +150  | °C         |

# **Recommended Operating Conditions**

The ZXMS6004FFQ is optimized for use with µC operating from 3.3V and 5V supplies.

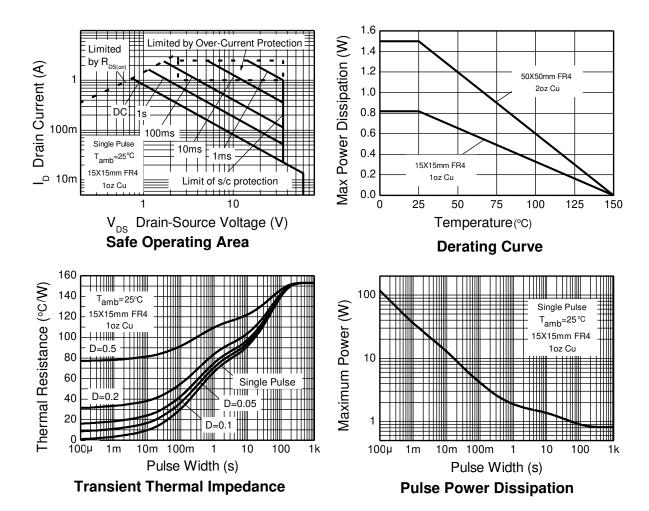
| Characteristic  | Symbol          | Min | Max  | Unit |
|---|-----------------|-----|------|------|
| Input Voltage Range   | VIN             | 0   | 5.5  | V    |
| Ambient Temperature Range                                     | TA              | -40 | +125 | °C   |
| High Level Input Voltage for MOSFET to be On                  | ViH             | 3   | 5.5  | V    |
| Low Level Input Voltage for MOSFET to be Off                  | V <sub>IL</sub> | 0   | 0.7  | V    |
| Peripheral Supply Voltage (Voltage to Which Load is Referred) | VP              | 0   | 36   | V    |

Notes:

- 5. For a device surface mounted on 15mm x 15mm single sided, 1oz weight copper on 1.6mm FR4 board, in still air conditions.
  6. For a device surface mounted on 50mm x 50mm single sided, 2oz weight copper on 1.6mm FR4 board, in still air conditions.
  7. Thermal resistance from junction and the mounting surfaces of the drain pins.



# **Typical Thermal Characteristics**





# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

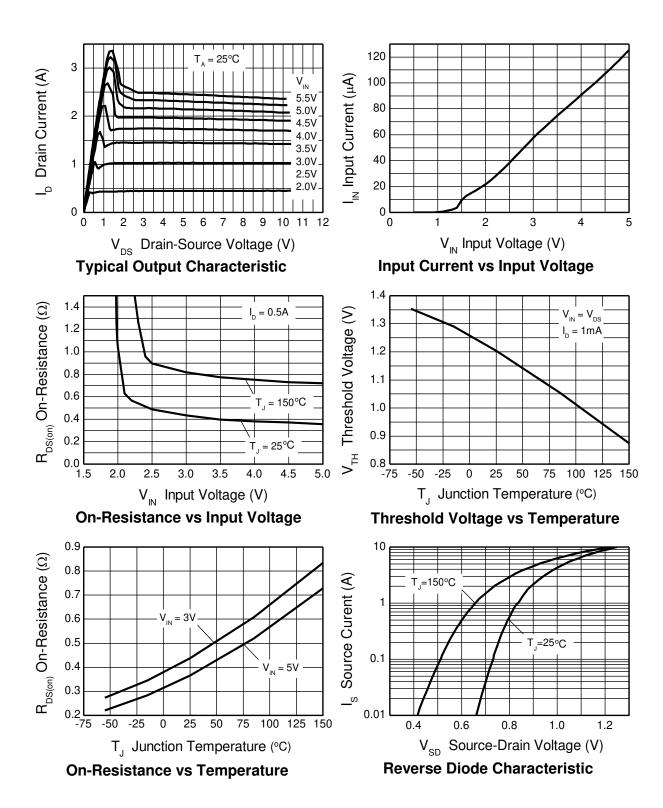
| Characteristic                             | Symbol                     | Min  | Тур  | Max | Unit  | Test Condition   |  |
|--|----------------------------|------|------|-----|-------|--|--|
| Static Characteristics                     |                            |      |      |     |       |  |  |
| Drain-Source Clamp Voltage                 | V <sub>DS(AZ)</sub>        | 60   | 65   | 70  | V     | $I_D = 10mA$   |  |
| Off-State Drain Current                    | IDSS                       | _    | _    | 500 | nA    | V <sub>DS</sub> = 12V, V <sub>IN</sub> = 0V                        |  |
| Oil-State Drain Current                    |                            | _    | _    | 1   | μΑ    | $V_{DS} = 36V, V_{IN} = 0V$  |  |
| Input Threshold Voltage                    | V <sub>IN(TH)</sub>        | 0.7  | 1    | 1.5 | V     | $V_{DS} = V_{GS}$ , $I_{D} = 1mA$                                  |  |
| long t Coverant                            | lin                        | _    | 60   | 100 |       | $V_{IN} = +3V$   |  |
| Input Current                              |                            | _    | 120  | 200 | μA    | $V_{IN} = +5V$   |  |
| Input Current while Overtemperature Active | _                          | _    | _    | 220 | μΑ    | $V_{IN} = +5V$   |  |
| Static Drain-Source On-State Resistance    | _                          | _    | 400  | 600 | mΩ    | $V_{IN} = +3V, I_D = 0.5A$   |  |
| Static Diani-Source On-State nesistance    | RDS(ON)                    | _    | 350  | 500 | 11122 | $V_{IN} = +5V, I_D = 0.5A$   |  |
| Continuous Drain Current (Note 5)          | ID                         | 0.9  | _    | _   |       | $V_{IN} = 3V, T_A = +25^{\circ}C$                                  |  |
| Continuous Brain Current (Note 3)          |                            | 1.0  | _    | _   | Α     | $V_{IN} = 5V, T_A = +25^{\circ}C$                                  |  |
| Continuous Drain Current (Note 6)          |                            | 1.2  | _    | _   | A     | V <sub>IN</sub> = 3V, T <sub>A</sub> = +25°C                       |  |
| Continuous Drain Current (Note 6)          |                            | 1.3  | _    | _   |       | $V_{IN} = 5V, T_A = +25^{\circ}C$                                  |  |
| Current Limit (Note 9)                     | I <sub>D(LIM)</sub>        | 0.7  | 1.7  |     | Α     | $V_{IN} = +3V$   |  |
| Current Limit (Note 8)                     |                            | 1    | 2.2  | _   | A     | $V_{IN} = +5V$   |  |
| Dynamic Characteristics                    | Dynamic Characteristics    |      |      |     |       |  |  |
| Turn-On Delay Time                         | td(ON)                     | _    | 5    | _   |       |  |  |
| Rise Time                                  | t <sub>R</sub>             | -    | 10   | _   |       | V <sub>DD</sub> = 12V, I <sub>D</sub> = 0.5A, V <sub>GS</sub> = 5V |  |
| Turn-Off Delay Time                        | tD(OFF)                    | _    | 45   | _   | μs    | VDD = 12V, ID = 0.5A, VGS = 5V                                     |  |
| Fall Time                                  | fF                         | _    | 15   | _   |       |  |  |
| Overtemperature Protection                 | Overtemperature Protection |      |      |     |       |  |  |
| Thermal Overload Trip Temperature (Note 9) | TJT                        | +150 | +175 | _   | °C    | _  |  |
| Thermal Hysteresis (Note 9)                |                            | _    | +10  |     | °C    |  |  |

Notes:

- 5. For a device surface mounted on 15mm x 15mm single sided, 1oz weight copper on 1.6mm FR4 board, in still air conditions. 6. For a device surface mounted on 50mm x 50mm single sided, 2oz weight copper on 1.6mm FR4 board, in still air conditions.
- 7. Thermal resistance from junction and the mounting surfaces of the drain pins.
- 8. The drain current is restricted only when the device is in saturation (see graph 'Typical Output Characteristic'). This allows the device to be used in the fully on-state without interference from the current limit. The device is fully protected at all drain currents, as the low power dissipation generated outside saturation makes current limit unnecessary.
- 9. Overtemperature protection is designed to prevent device destruction under fault conditions. Fault conditions are considered as "outside" normal operating range, so this part is not designed to withstand over-temperature for extended periods.

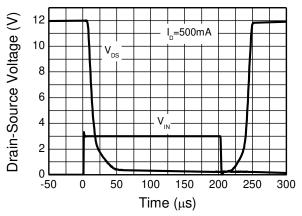


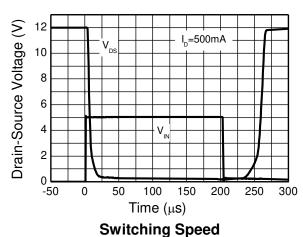
#### **Typical Performance Characteristics**





# **Typical Performance Characteristics** (continued)





### **Switching Speed**

2.5  $V_{IN} = 5V$ I<sub>D</sub> Drain Current (A)  $V_{DS} = 15V$ 2.0  $R_D = 0\Omega$ 1.5 1.0 0.5 0.0 10 0 5 15 20 Time (ms)

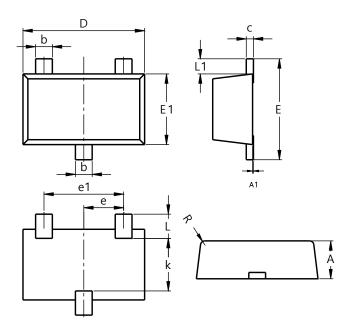
**Typical Short Circuit Protection** 



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23F

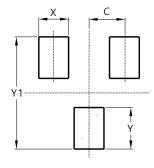


| SOT23F               |          |      |      |  |  |
|----------------------|----------|------|------|--|--|
| Dim                  | Min      | Max  | Тур  |  |  |
| Α                    | 0.80     | 1.00 | 0.90 |  |  |
| A1                   | 0.00     | 0.10 | 0.01 |  |  |
| b                    | 0.35     | 0.50 | 0.44 |  |  |
| С                    | 0.10     | 0.20 | 0.16 |  |  |
| D                    | 2.80     | 3.00 | 2.90 |  |  |
| е                    | 0.95 REF |      |      |  |  |
| e1                   | 1.90 REF |      |      |  |  |
| Е                    | 2.30     | 2.50 | 2.40 |  |  |
| E1                   | 1.50     | 1.70 | 1.65 |  |  |
| k                    | 1.20     |      |      |  |  |
| L                    | 0.30     | 0.65 | 0.50 |  |  |
| L1                   | 0.30     | 0.50 | 0.40 |  |  |
| R                    | 0.05     | 0.15 | -    |  |  |
| All Dimensions in mm |          |      |      |  |  |

# **Suggested Pad Layout**

 $Please\ see\ http://www.diodes.com/package-outlines.html\ for\ the\ latest\ version.$ 

#### SOT23F



| Dimensions | Value (in mm) |  |  |
|------------|---------------|--|--|
| С          | 0.95          |  |  |
| Х          | 0.80          |  |  |
| Y          | 1.110         |  |  |
| Y1         | 3.000         |  |  |



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